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## Phosphinecarboxamide based InZnP QDs – an air tolerant route to luminescent III–V semiconductors†

Yi Wang,<sup>a</sup> Jack Howley,<sup>b</sup> Erica N. Faria,<sup>b</sup> Chen Huang,<sup>cd</sup> Sadie Carter-Searjeant,<sup>a</sup> Simon Fairclough,<sup>e</sup> Angus Kirkland,<sup>cd</sup> Jason J. Davis,<sup>g</sup> Falak Naz,<sup>f</sup> Muhammad Tariq Sajjad,<sup>id f</sup> Jose M. Goicoechea<sup>\*h</sup> and Mark Green<sup>id \*</sup>

**We describe a new synthetic methodology for the preparation of high quality, emission tuneable InP-based quantum dots (QDs) using a solid, air- and moisture-tolerant primary phosphine as a group-V precursor. This presents a significantly simpler synthetic pathway compared to the state-of-the-art precursors currently employed in phosphide quantum dot synthesis which are volatile, dangerous and air-sensitive, e.g. P(Si(CH<sub>3</sub>)<sub>3</sub>)<sub>3</sub>.**

The advent of modern quantum dots (QD) as technologically relevant materials can be traced back to 1993, when a landmark paper married organometallic chemistry and high temperature, inert atmosphere, solution-based synthesis, resulting in II–VI nanomaterials of a previously unobtainable quality.<sup>1</sup> The success of this route can be directly related to the reagents employed, specifically developed as solution analogues of vapour phase precursors for high quality semiconducting materials. Whilst the group II elements were initially supplied *via* a metal alkyl, Steigerwald's 'masked atom' approach to group VI elements using alkylphosphine chalcogenides can be seen as a pioneering step that made chalcogenides routinely available in organic solvent-based, high temperature nanoparticle

### New concepts

Quantum dots (QDs) are ubiquitous and are now considered a well-developed technology, although most are based on a toxic metal system – cadmium selenide. The obvious replacement is indium phosphide, however, the synthetic chemistry in the synthesis of InP based QDs has barely developed in over three decades since 1989, and uses the highly reactive, dangerous, volatile, air-sensitive phosphorous precursor tris(trimethylsilyl)phosphine. In our report, we describe the use of an air tolerant, solid phosphorous precursor that is relatively simple and safe to use, allowing manipulations of the precursors in ambient conditions on the bench prior to QD synthesis. The resulting QDs are emission tuneable, brightly emitting and this synthetic development can fit directly into existing QD chemistry notably in the manufacture of engineered core/shell architectures. This greatly improves the ease of QD synthesis, both in the lab and potentially in industry.

synthesis.<sup>2</sup> However, cadmium chalcogenide QDs are unlikely to be widely adopted due to recent regulations and general concerns regarding the use of toxic metals.<sup>3</sup>

Group III–V semiconducting compounds (notably InP) provide an attractive alternative to cadmium-based nanomaterials, with recent studies describing InP-based QD with optical properties comparable to their II–VI analogues.<sup>4</sup> However, the basic synthetic chemistry remains essentially unchanged for over 30 years. In landmark reports, the dehalosilylation reaction, first reported by Healy *et al.*<sup>5</sup> and by Wells *et al.*<sup>6</sup> in 1989 described solution routes to III–V materials exploiting the volatile, highly pyrophoric and reactive liquids E(Si(CH<sub>3</sub>)<sub>3</sub>)<sub>3</sub> (E = P, As) as solution equivalents to phosphine or arsine gas (PH<sub>3</sub> or AsH<sub>3</sub>). This precursor chemistry was developed for the preparation of III–V QDs by Mičić *et al.*<sup>7</sup> and Olshavsky *et al.*<sup>8</sup> and has since been globally adopted. Whilst other precursor routes based on alternative phosphorous delivery methods do exist, the majority are unlikely to find routine application as they are equally difficult and problematic. The use of aminophosphines is notable yet presents only a marginal

<sup>a</sup> Department of Physics, King's College London, The Strand, London, WC2R 2LS, UK. E-mail: mark.a.green@kcl.ac.uk

<sup>b</sup> Department of Chemistry, Chemistry Research Laboratory, University of Oxford, Mansfield Road, Oxford, OX1 3TA, UK

<sup>c</sup> Department of Materials, University of Oxford, Parks Road, Oxford, OX1 3PH, UK

<sup>d</sup> Electron Physical Sciences Imaging Centre, Diamond Light Source, Harwell Science Innovation Campus, Fermi Ave, Didcot, OX110DE, UK

<sup>e</sup> Department of Materials Science and Metallurgy, University of Cambridge, 27 Charles Babbage Road, Cambridge, CB3 0FS, UK

<sup>f</sup> London Centre for Energy Engineering (LCEE), School of Engineering, London South Bank University, 103 Borough Road, London, SE1 0AA, UK

<sup>g</sup> Physical and Theoretical Chemistry Laboratory, South Parks Road, Oxford, OX1 3QZ, UK

<sup>h</sup> Department of Chemistry, Indiana University, 800 E. Kirkwood Ave., Bloomington, IN, 47405, USA. E-mail: jgoicoec@iu.edu

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improvement, as these similarly volatile liquids yield complicated phosphorous products under thermolysis,<sup>9</sup> whilst the oxides of aminophosphines have been shown to be toxic.<sup>10</sup> In addition, common reagents such as  $\text{P}(\text{Si}(\text{CH}_3)_3)_3$  have been shown to be excessively reactive, making it difficult to separate nucleation and focused growth steps. For these reasons, a stable reagent with a well-defined decomposition point that provides the volatile intermediate should allow discrete controlled nucleation not normally afforded by  $\text{P}(\text{Si}(\text{CH}_3)_3)_3$ .<sup>11,12</sup> To date, the lack of an obvious, well-defined and convenient group V precursor has limited the expansion of III–V based QD relative to their II–VI analogues.

Recently, sodium phosphoethynolate has been used as a new phosphorus precursor to InP quantum dots.<sup>13</sup> NaPCO is not pyrophoric and may be handled under ambient conditions for several hours before decomposing, making it attractive compared to traditional precursors. Phosphinecarboxamide,  $\text{PH}_2\text{C}(\text{O})\text{NH}_2$ ,<sup>14</sup> is readily derived from NaPCO by reaction with ammonium tetrafluoroborate in liquid ammonia and has the advantage of being a metal-free precursor. Phosphinecarboxamide has been used as a phosphorus precursor for the chemical vapor deposition (CVD) of zinc phosphide thin films.<sup>15</sup> It was suggested that upon heating, phosphinecarboxamide decomposed to form  $\text{PH}_3$  (alongside isocyanic acid,  $\text{HNCO}$ ), which then reacted with zinc salts to form zinc phosphide. This ‘masked’  $\text{PH}_3$  reactivity is particularly relevant for III–V QD synthesis, as  $\text{PH}_3$  is a known phosphorus precursor to InP. Li *et al.* showed that by acidification of  $\text{Ca}_3\text{P}_2$  with HCl, the gaseous  $\text{PH}_3$  generated can be reacted with indium salts in solution to form InP QDs.<sup>16</sup> We postulated that if ‘masked’  $\text{PH}_3$

reactivity could be reproduced in the solution phase, then phosphinecarboxamide should act as a suitable phosphorus source for InP QD synthesis.

We first explored the thermal decomposition of phosphinecarboxamide in solution by  $^{31}\text{P}$  NMR spectroscopy. Upon heating at 105 °C, decomposition was evidenced by a decrease in intensity of the characteristic  $^{31}\text{P}\{^1\text{H}\}$  signal at –134.9 ppm (Fig. 1a). The decomposition of PCA also gave rise to two new signals at –212.2 ppm and –240.8 ppm, which may be unambiguously assigned to  $\text{P}_2\text{H}_4$  and  $\text{PH}_3$ , respectively, from the proton-coupled spectrum (Fig. 1b). Further evidence of the *in situ* generation of  $\text{PH}_3$  was the formation of characteristic signals of InP clusters by  $^{31}\text{P}\{^1\text{H}\}$  NMR upon reaction with indium phenylacetate at 110 °C (–180 ppm to –250 ppm) (ESI,† Fig. S1). These magic-sized clusters (MSCs), such as  $\text{In}_{37}\text{P}_{20}(\text{COOPh})_{51}$  reported by Cossairt and co-workers, are well characterised intermediates in QD growth.<sup>17</sup> More recently, Zn-alloyed InP MSCs have been elucidated by Kwon *et al.*<sup>18</sup> The formation of InP clusters from phosphinecarboxamide was also characterized by UV-Vis spectroscopy, where a broad absorption shoulder was observed at *ca.* 410 nm (ESI,† Fig. S2).

It is worth noting at this stage that upon heating phosphinecarboxamide generates the  $\text{PH}_3$  which is in the desired oxidation state of –3, unlike the thermal decomposition products of  $\text{P}(\text{N}(\text{CH}_3)_2)_3$ , a common precursor, which generates both +3 and –3 species.<sup>9</sup> In this case, the comparison with TOPSe as a precursor falls short, as TOPSe arguably generates selenium in the Se(0) state – in fact, delivery of the reactive intermediate in the correct oxidation state is a key requirement, so the chemistry described here is perhaps more useful. When

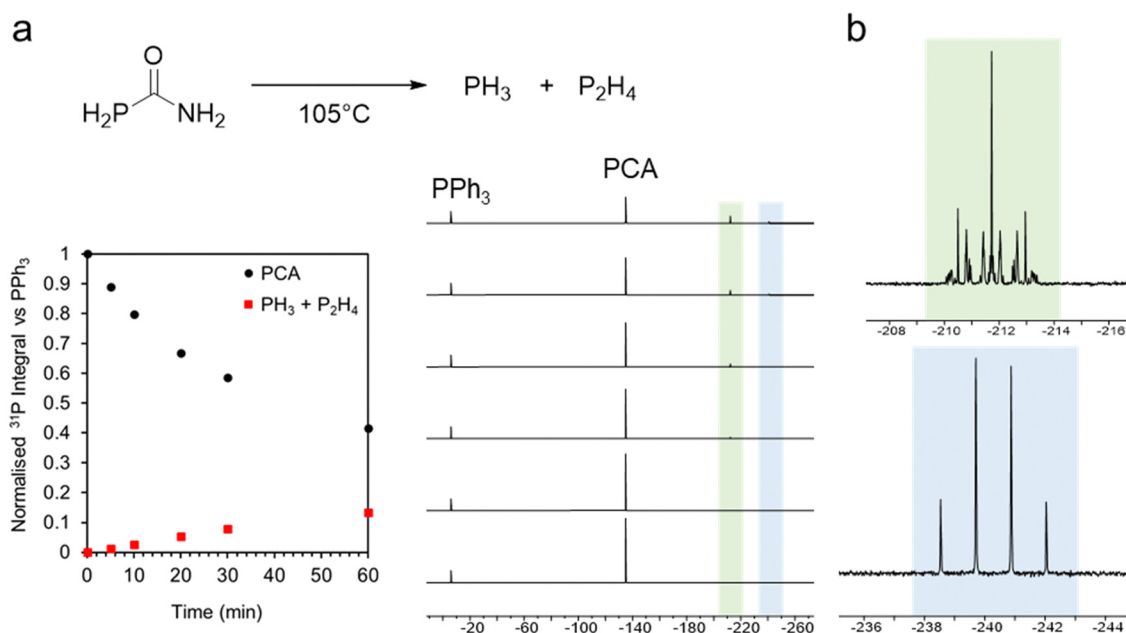
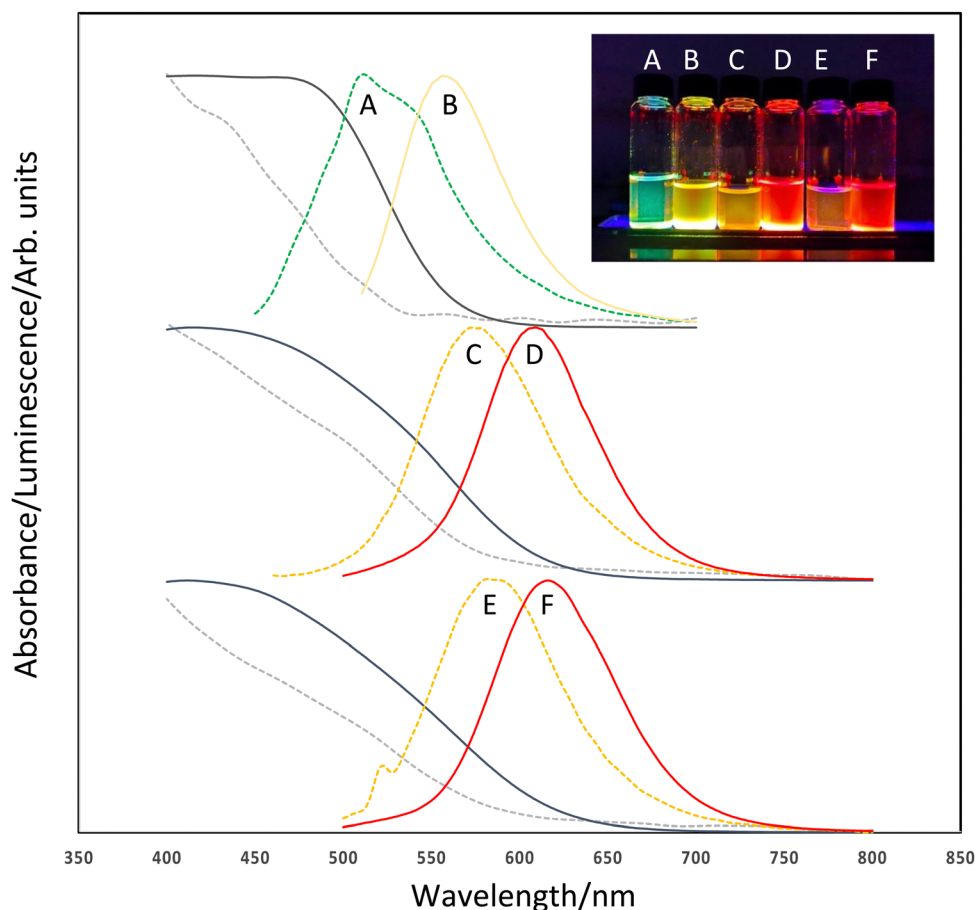


Fig. 1 (a) Thermal decomposition of  $\text{PH}_2\text{C}(\text{O})\text{NH}_2$  followed by  $^{31}\text{P}\{^1\text{H}\}$  NMR spectroscopy; (b)  $^{31}\text{P}$  NMR spectra of phosphorus-containing decomposition products  $\text{PH}_3$  (green) and  $\text{P}_2\text{H}_4$  (blue).



The reaction described here proceeded in two phases, with an initial degassing step of between 30 min and 60 minutes at 120 °C. This initial step had two functions, initially removing dissolved gasses and water, whilst initiating the *in situ* gradual

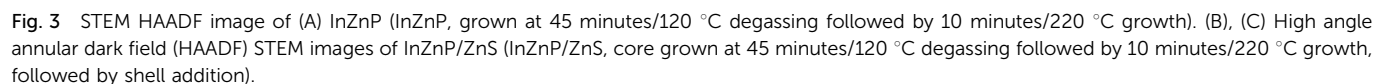
The optical properties of the resulting QD were consistent with InP-based nanomaterials with tuneable visible emission observed between the green and red regions of the visible spectrum when excited at 365 nm (Fig. 2). Absorption band



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Scanning transmission electron microscopy (STEM) of unshelled particles (InZnP, grown at 45 minutes/120 °C degassing followed by 10 minutes/220 °C growth) showed typical images associated with nanoscale InZnP, with small, discrete, slightly anisotropic particles *ca.*  $3.0 \pm 0.1$  nm in diameter, as shown in Fig. 3a. Elemental analysis (ESI,<sup>†</sup> Fig. S3) confirmed the presence of In, Zn, P, C and O; carbon being attributed to the decomposed capping ligand (hexadecylamine) whilst the oxygen being assigned to a surface oxide species. Previous work

The use of a solid, air-tolerant phosphorous precursor makes InP QD significantly easier to prepare, and such an approach might be considered the functional equivalent of trioctylphosphine selenide (TOPSe) acting as a convenient selenium source, as both precursors are relatively stable at room temperature yet act as an efficient precursor source when heated. Whilst detailed studies have uncovered complex reaction mechanisms for the preparation of Cd and Pb-based QDs using trialkylphosphine chalcogenides,<sup>26,27</sup> the rationale for





our study remains identical – a stable compound which provides a convenient, controllable route to a hitherto relatively inaccessible element/precursor when required in solution semiconductor synthesis.

Phosphinecarboxamide is unusually an air- and moisture-tolerant primary phosphine, which we have shown decomposes to phosphine and diphosphane. The relatively rare stability of primary phosphines is assigned to either steric factors, or the electronic structure which can be engineered, by, for example, the inclusion of heteroatoms that shift the HOMO. The energy of the singly occupied molecular orbital (SOMO) of radical cations has been shown to be a relevant indicator of stability, with a suggested threshold of  $-10$  eV being the criterion.<sup>28</sup> It is worth noting that PCA is not entirely stable and will slowly decompose under ambient conditions over an extended period. Since steric factors are clearly not relevant, the extended stability of PCA has been attributed by Jupp partly to resonance stabilisation of the phosphorus lone pair by the adjacent amide moiety.<sup>29</sup>

In conclusion, we describe the use of a simple, air and moisture tolerant primary phosphine as a convenient precursor for indium phosphide-based QD. The resulting zinc blende crystalline nanomaterials had optical properties which could be tuned through the green/red range of the visible spectrum. This pathway presents a shift in synthetic methodology away from volatile phosphorous compounds towards engineered stable, solid precursors which remain inert until desired in the specific reaction. This precursor route highlights the suitability of specific simple phosphines as convenient precursors towards high quality semiconducting nanomaterials.

## Conflicts of interest

There are no conflicts to declare.

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